

EE-606: Solid State Devices

Lecture 7: Energy Bands in Real Crystals

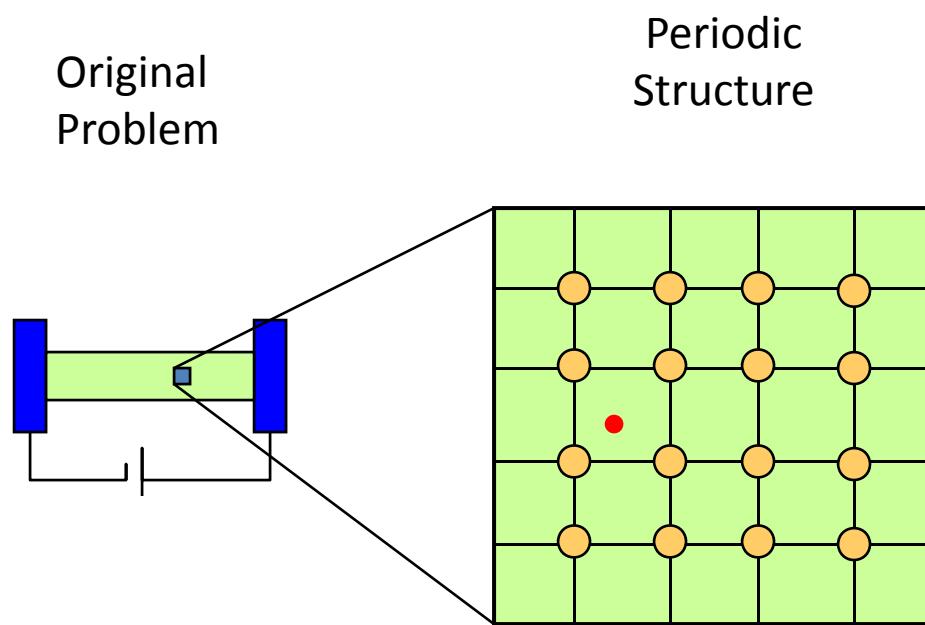
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Outline

- 1) E-k diagram/constant energy surfaces in 3D solids**
- 2) Characterization of E-k diagram: Bandgap
- 3) Characterization of E-k diagram: Effective Mass
- 4) Conclusions

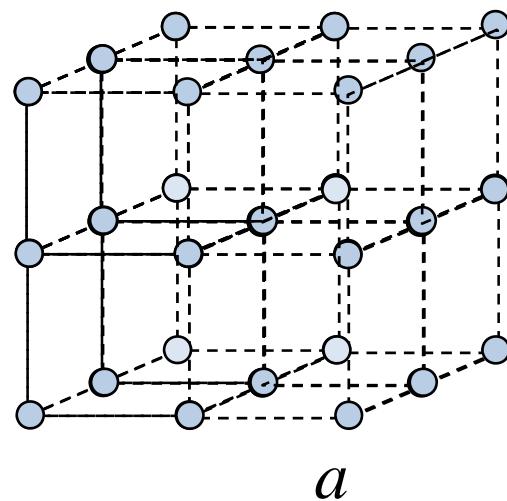
Reference: Vol. 6, Ch. 3 (pages 71-77)

Electronic States

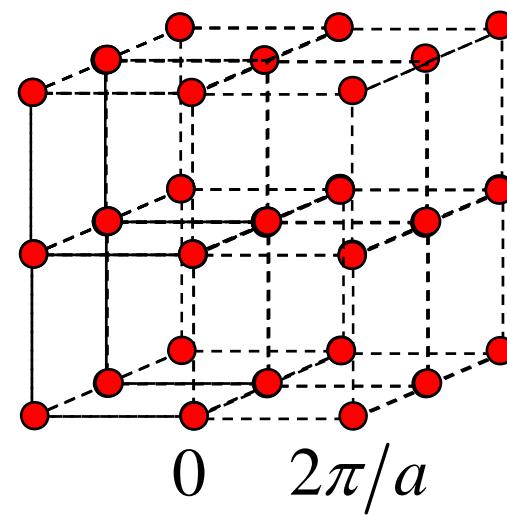


Brillouin Zone in Cubic Lattice ...

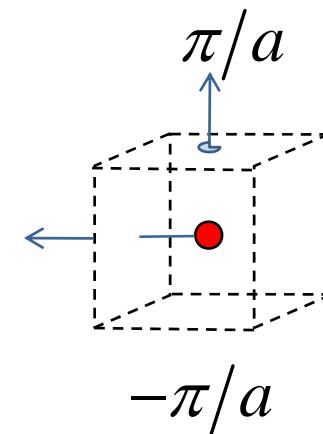
Real Space
Cubic Lattice



Reciprocal Lattice



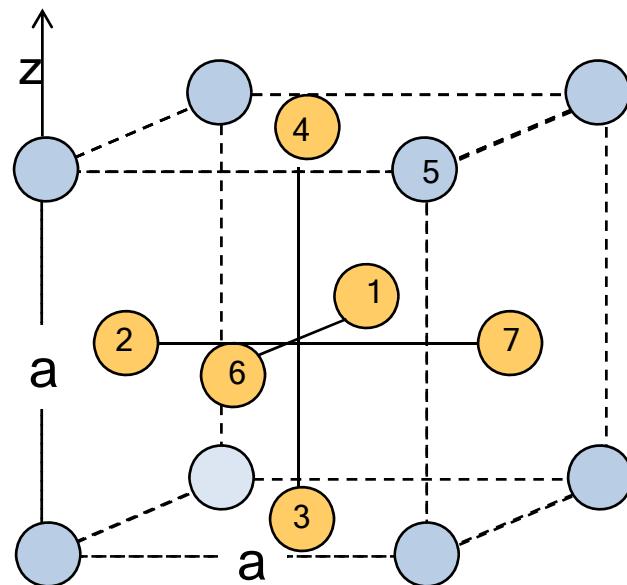
Brillouin Zone



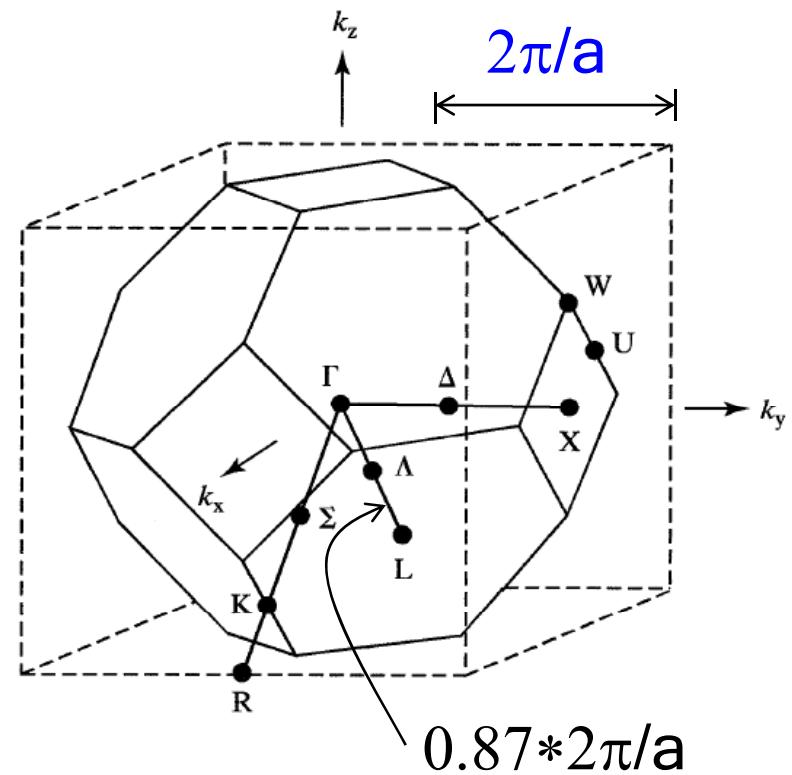
Follow W-S algorithm, but
now for reciprocal lattice

Brillouin Zone in Real FCC Lattices ...

Real Space FCC
(for Si, Ge, GaAs)

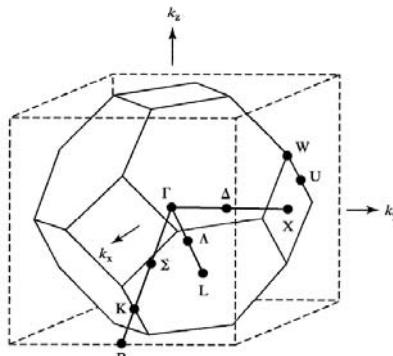


Reciprocal Lattice

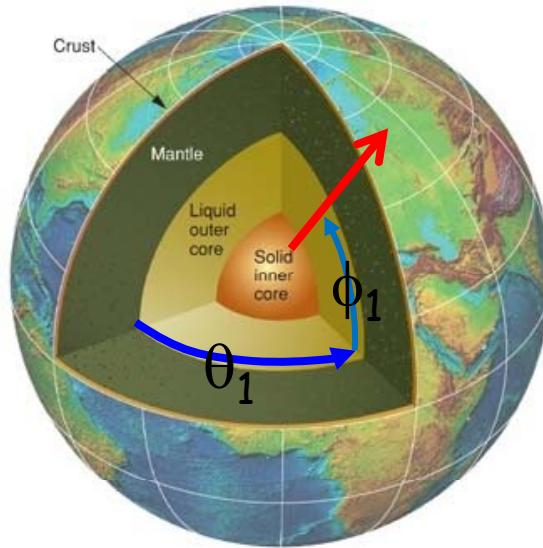


Note unlike cubic lattice, zone edge is not at π/a

Analogy for E-k Diagram: 4D info through 2D Plots

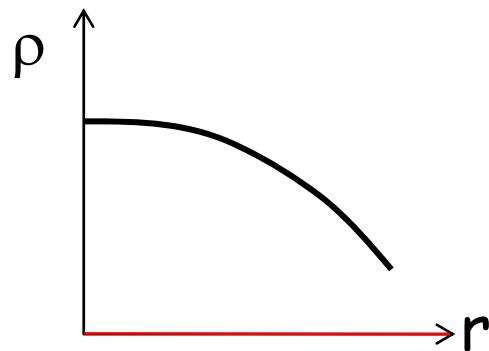


Density (x,y,z)
4D information

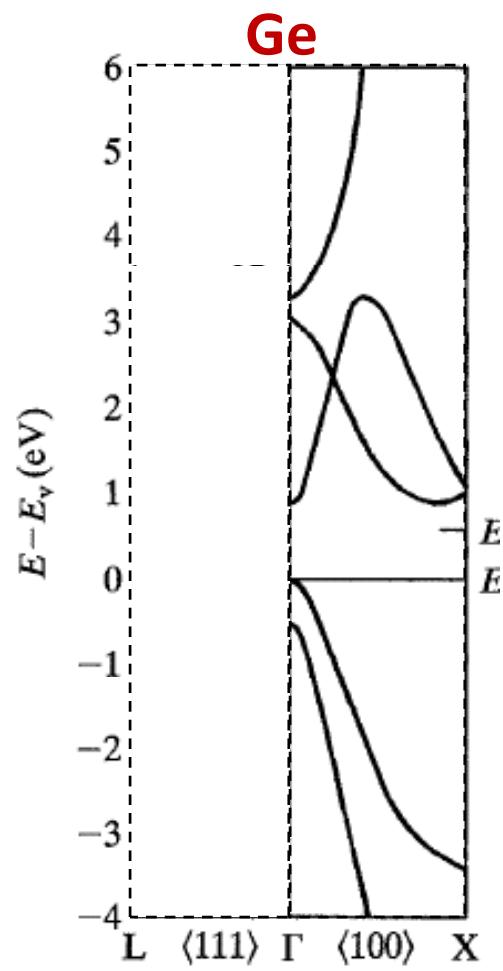
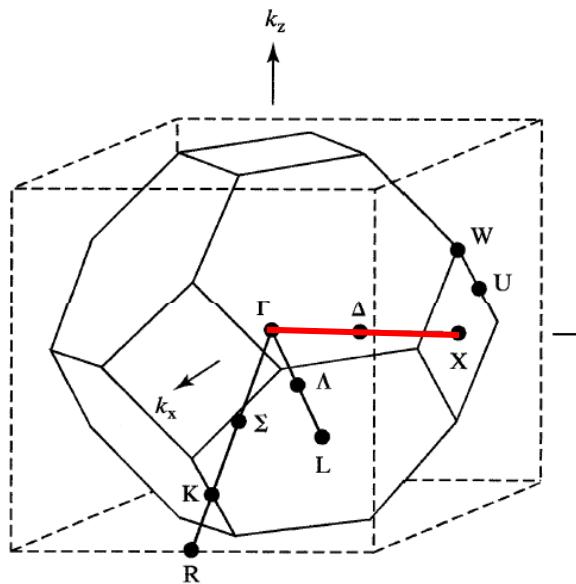


A series of line-sections can
Represent the 4D info in 2D plots

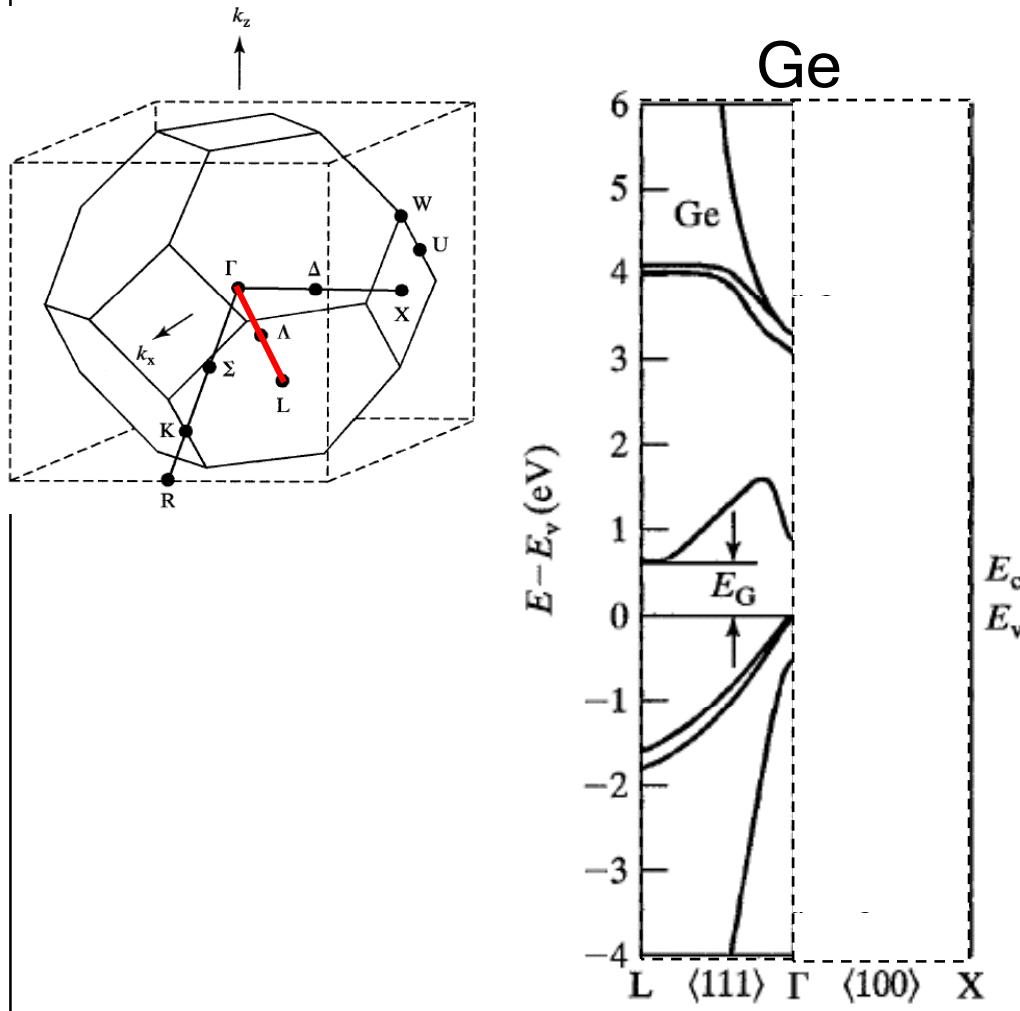
Cut along $(\theta_1, \phi_1) \dots$



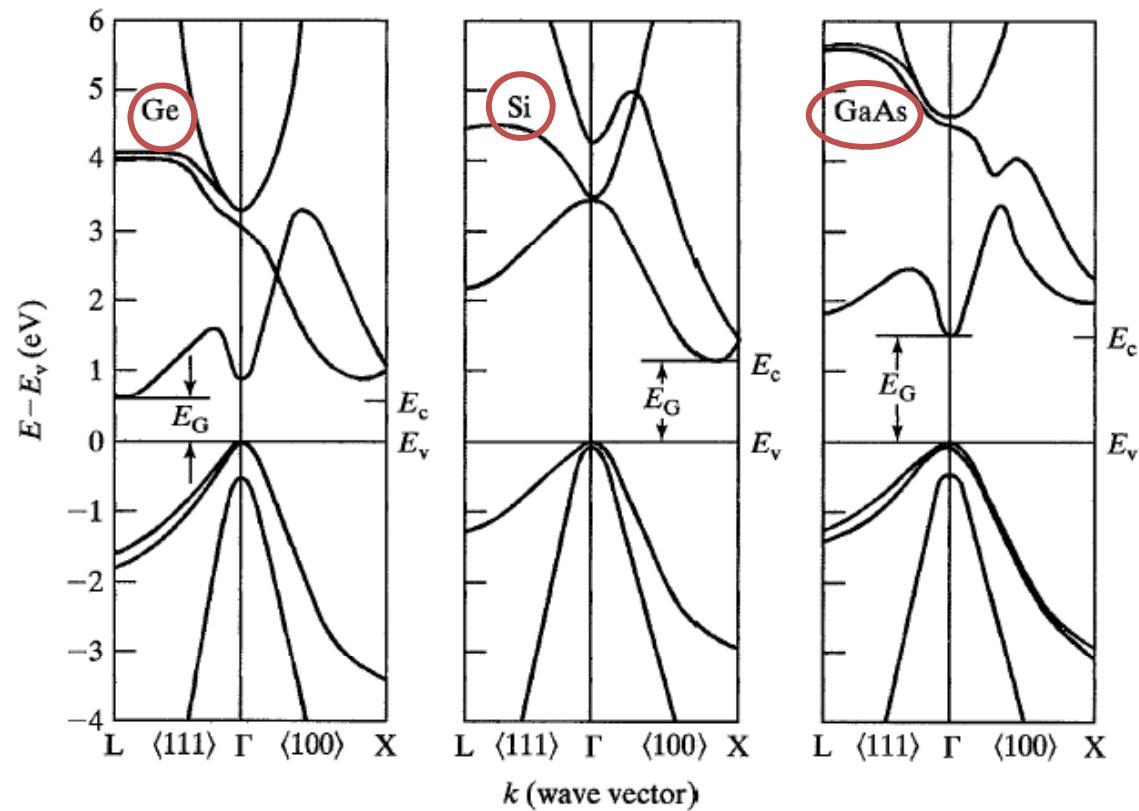
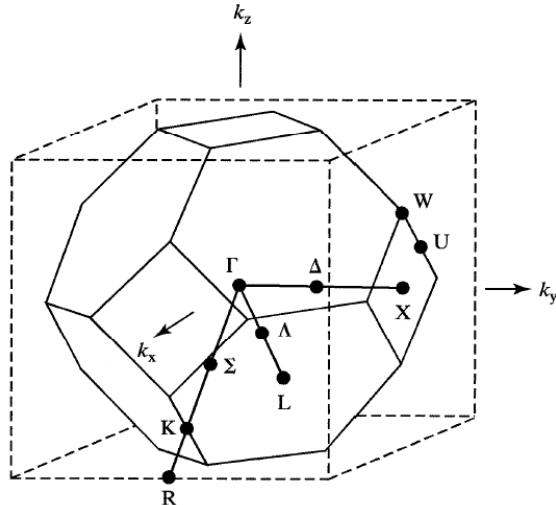
E-k along Γ -X Direction



E-k along Γ -L direction

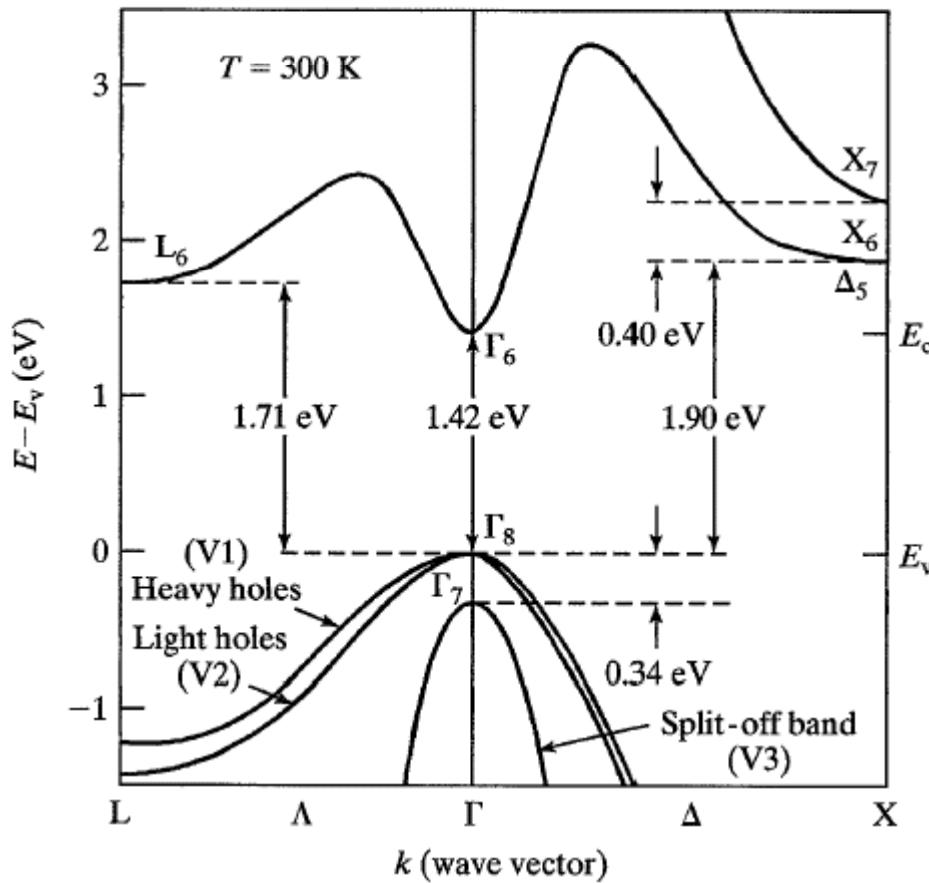


E-k Diagram



- 3 valence bands (light hole, heavy hole, split-off)
valence bands near $k=0$ is essentially $E \sim k^2$
- Minima may not be at zone center
- (Ge: 8 L valleys, Si: 6 X valleys, and GaAs: Γ valleys)

E-k diagram for GaAs

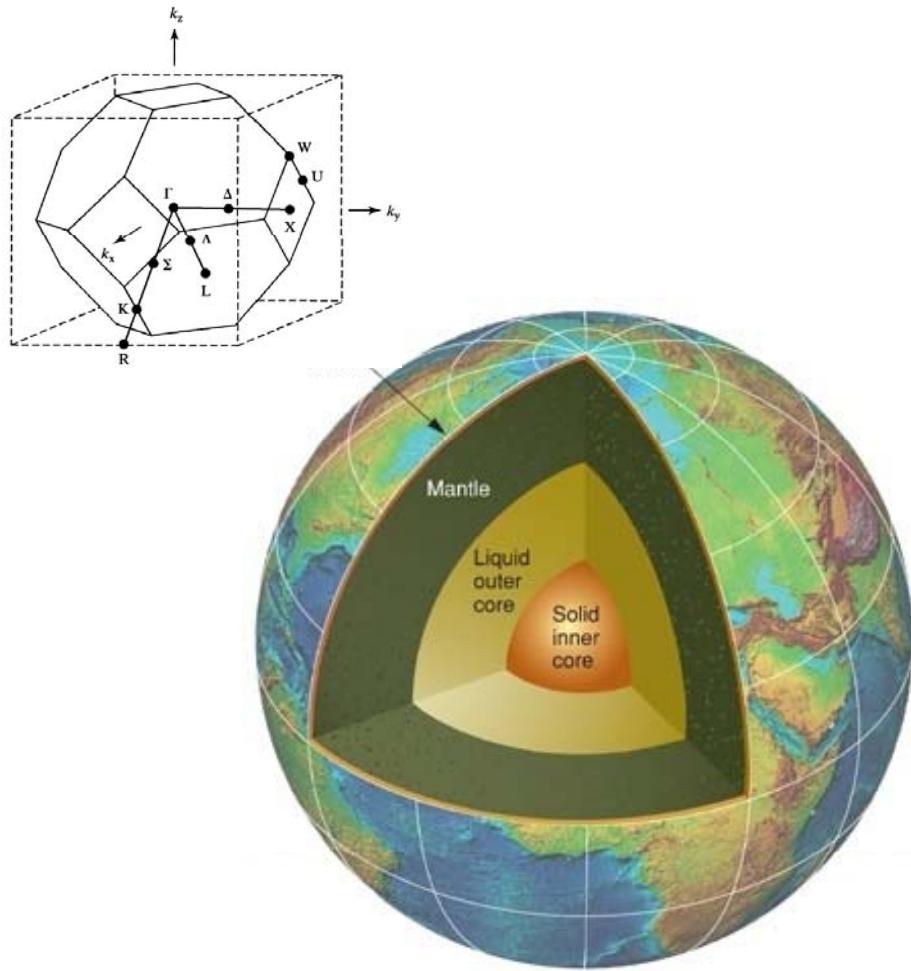


Direct bandgap material

Zone-edge gaps ($L_6-\Gamma_8$,
 $X_6-\Gamma_8$) close to direct gap

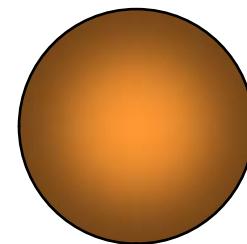
Has important implications
For transport

Analogy for E-k Diagram

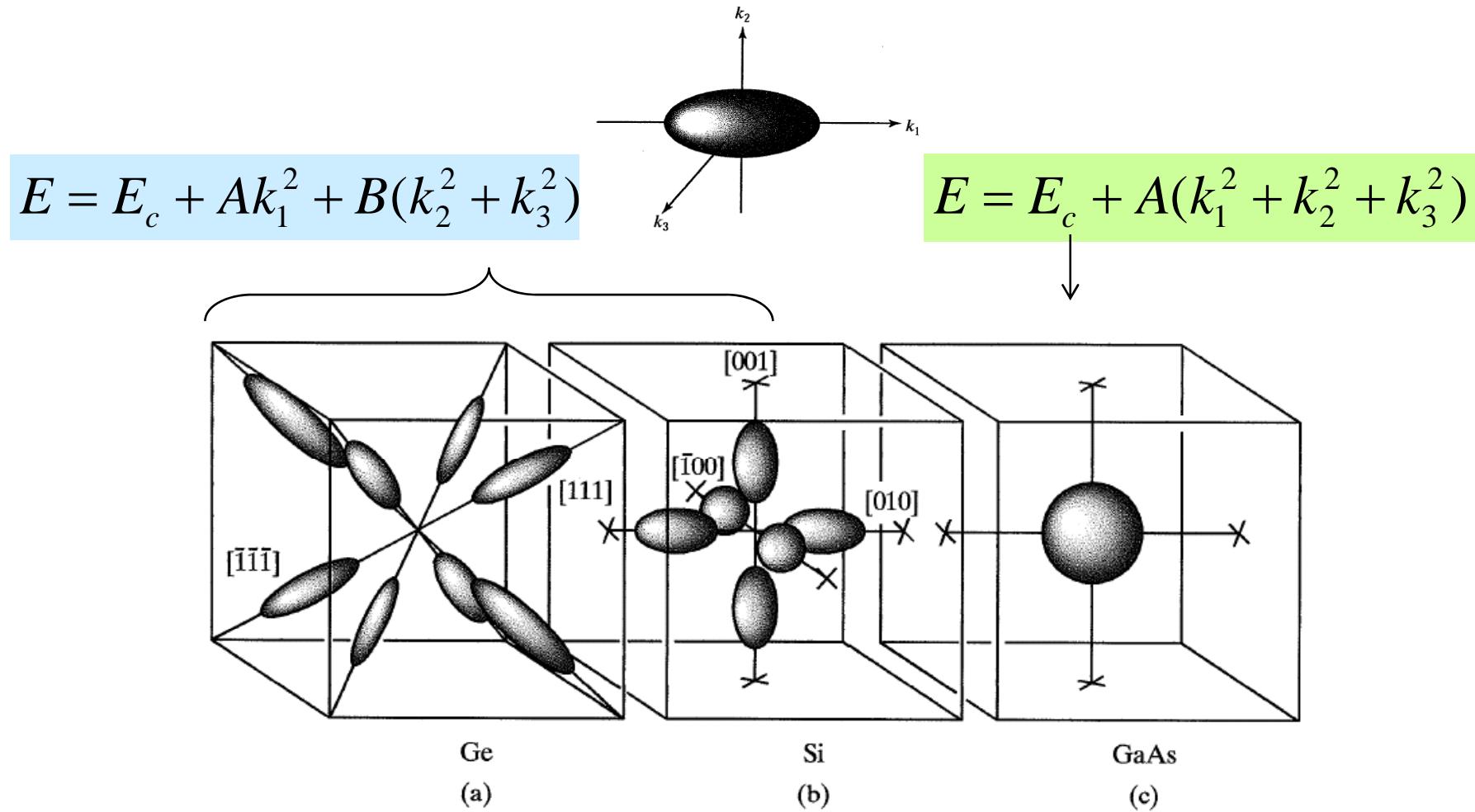


Density (x,y,z)

Contours of density



Constant-E surface for Conduction Band



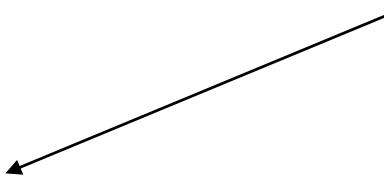
Constant E-surface ...

$$E = E_c + \textcolor{red}{A}k_1^2 + \textcolor{blue}{B}(k_2^2 + k_3^2)$$

$$E = E_c + \textcolor{red}{A}(k_1^2 + k_2^2 + k_3^2)$$



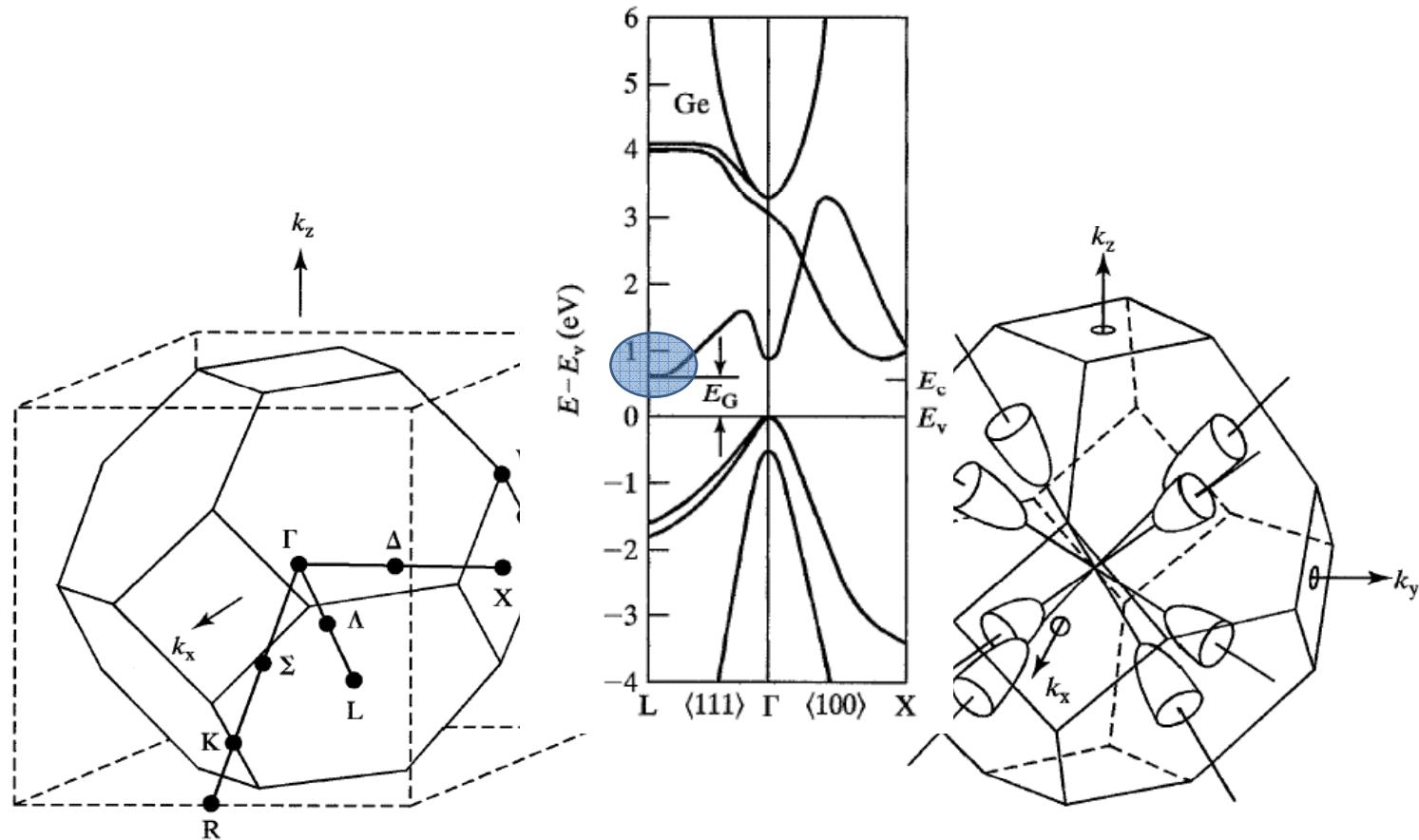
$$\frac{1}{m_{ij}} = \frac{1}{\hbar^2} \frac{\partial^2 E}{\partial k_i \partial k_j}$$



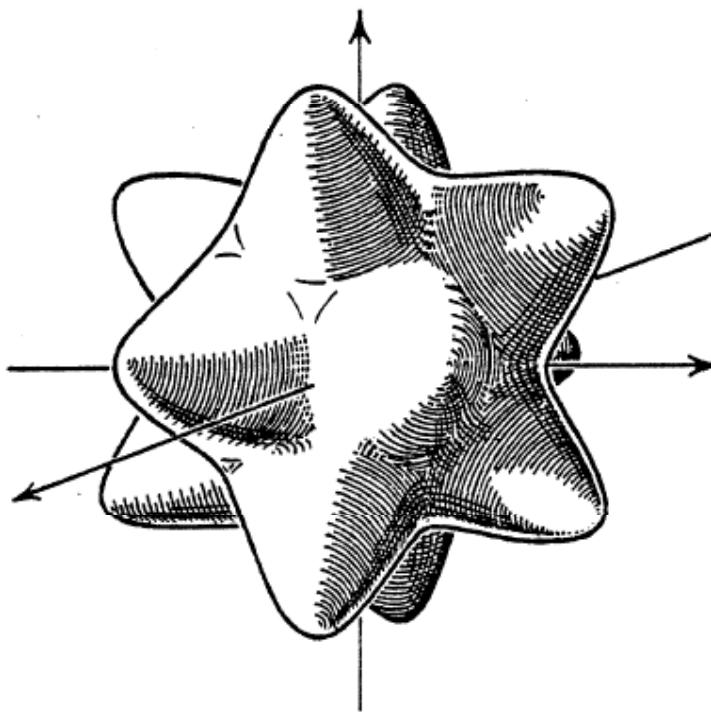
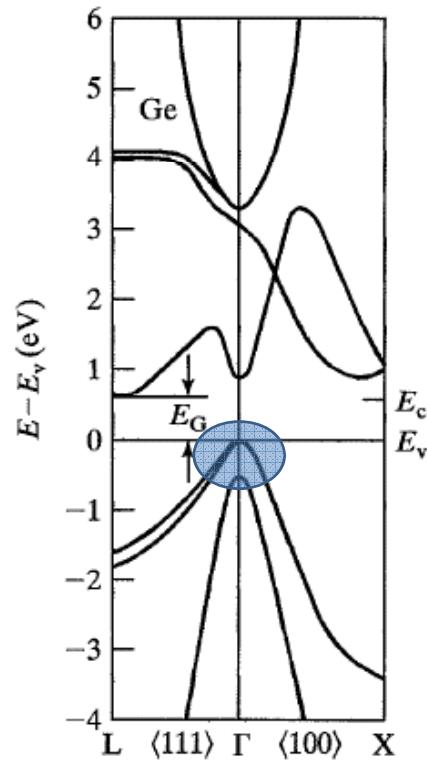
$$\frac{1}{m_{11}} = \frac{2A}{\hbar^2}; \quad \frac{1}{m_{22}} = \frac{1}{m_{33}} = \frac{2B}{\hbar^2}; \quad \frac{1}{m_{ij}} (i \neq j) = 0$$

$$\frac{1}{m_{11}} = \frac{1}{m_{22}} = \frac{1}{m_{33}} = 2A; \quad \frac{1}{m_{ij}} (i \neq j) = 0$$

Four valleys inside BZ for Germanium



Constant E-surface for Valence Band



$$E = E_v - Ak^2 \mp \sqrt{[B^2 k^4 + C^2(k_x^2 k_y^2 + k_y^2 k_z^2 + k_z^2 k_x^2)]}$$

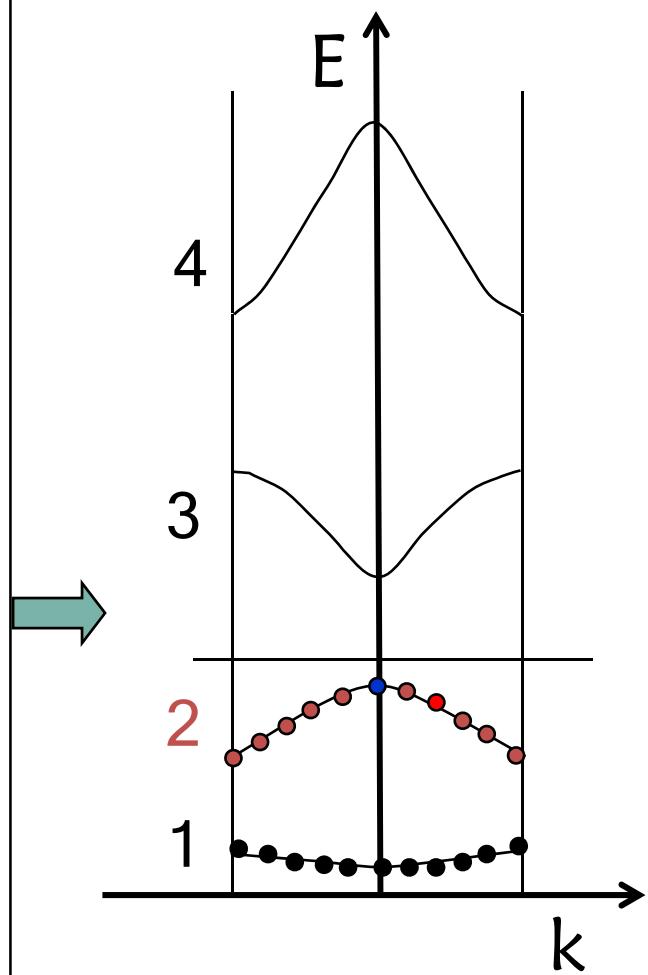
Si: $A=4.29, B=0.68, C=4.87$; Ge: $A=13.38, B=8.48, C=13.15$

Outline

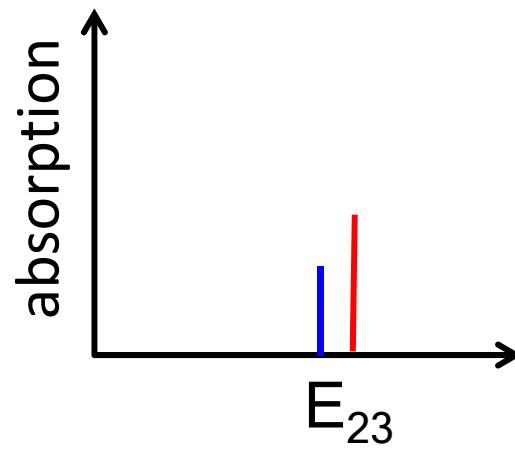
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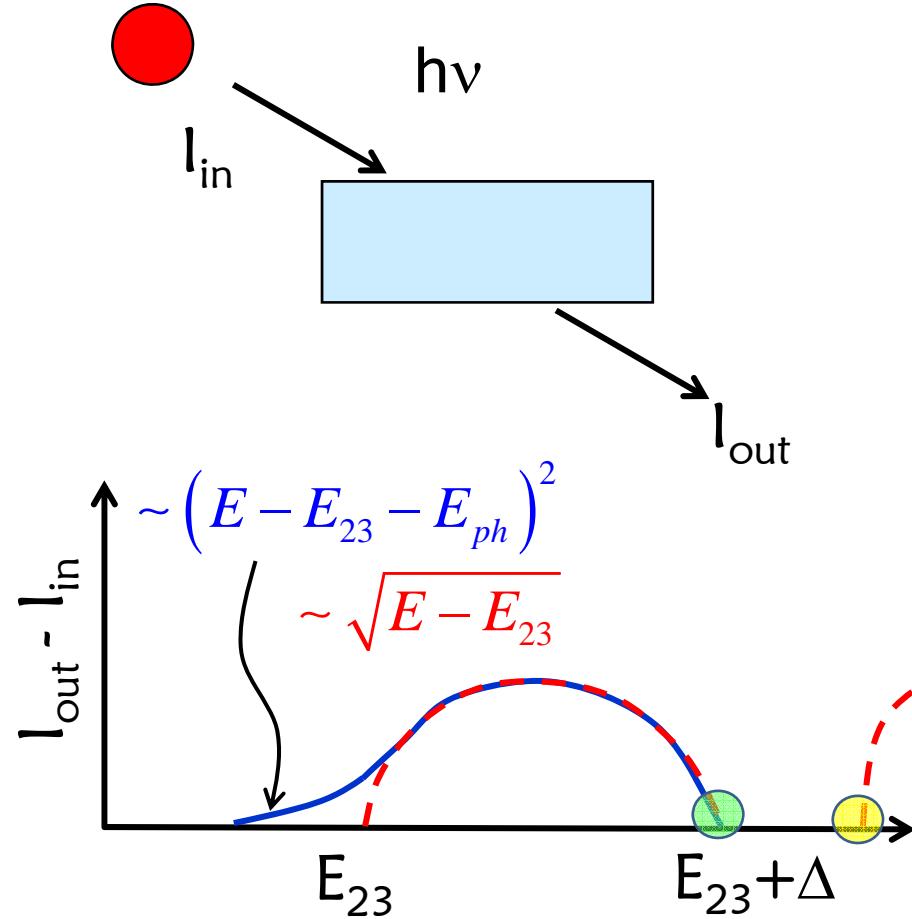
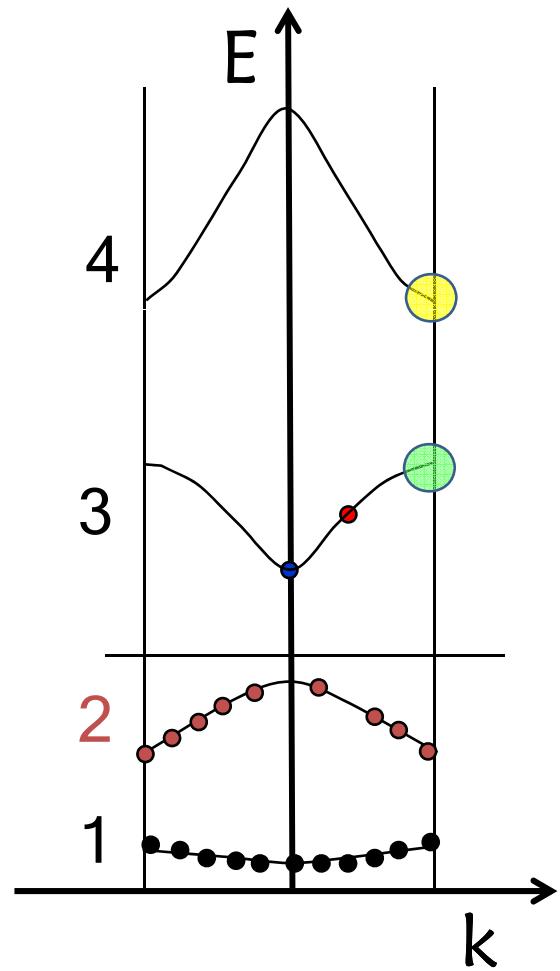
Measurement of Band Gap



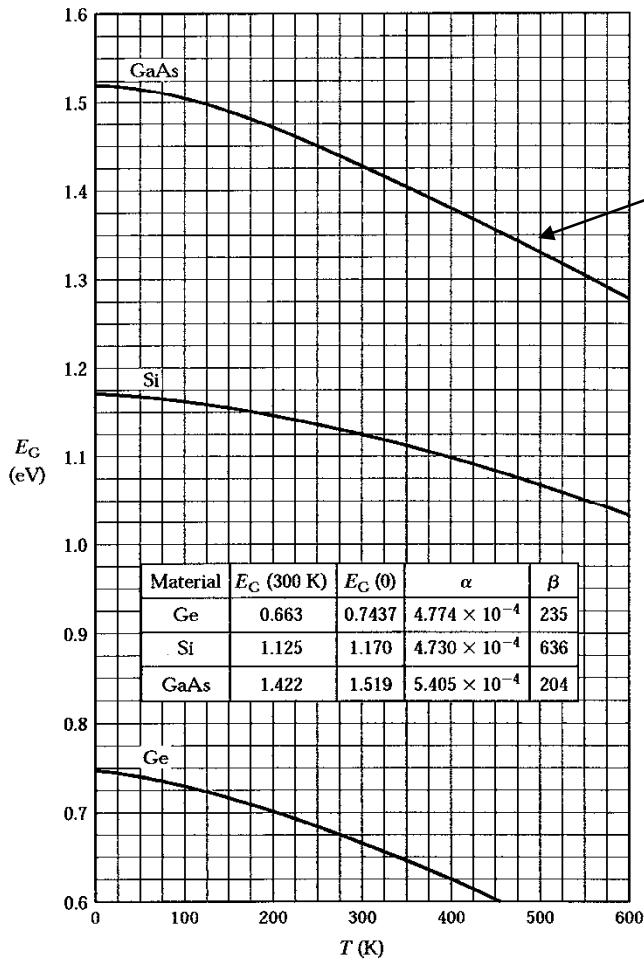
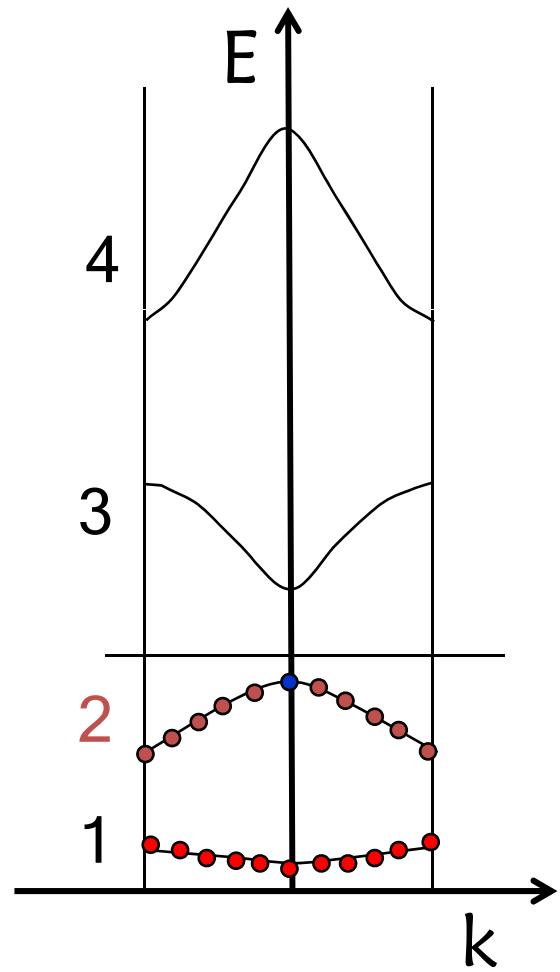
Photons are only absorbed between bands that have filled and empty states



Measurement of Energy Gap



Temperature-dependent Band Gap

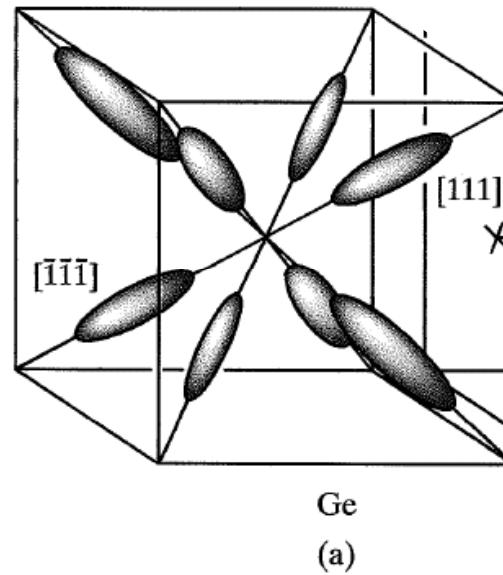
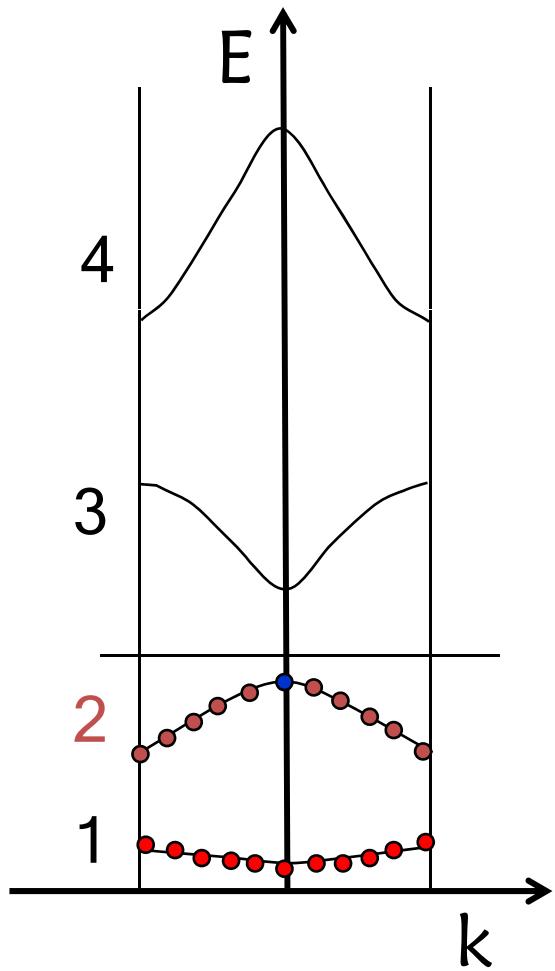


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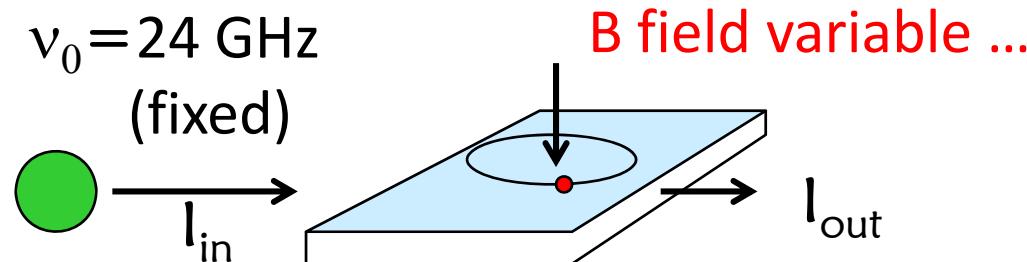
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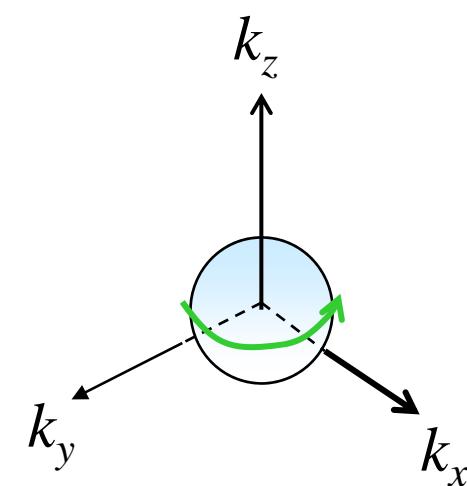
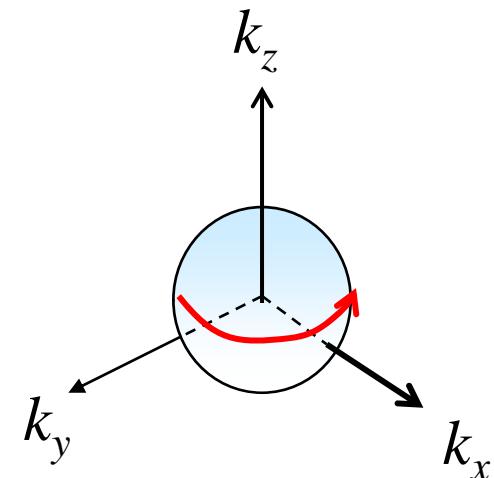
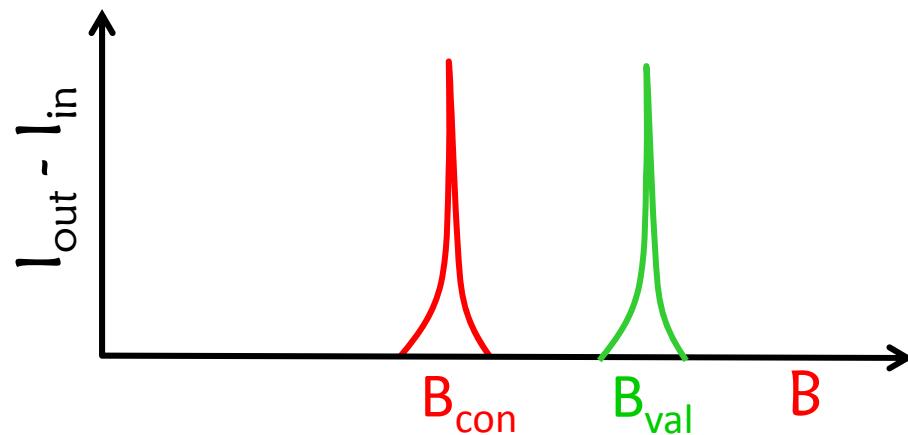
Measurement of Effective Mass



Measurement of Effective Mass



$$v_0 = \frac{qB_0}{2\pi m^*} \quad m^* = \frac{qB_0}{2\pi v_0}$$

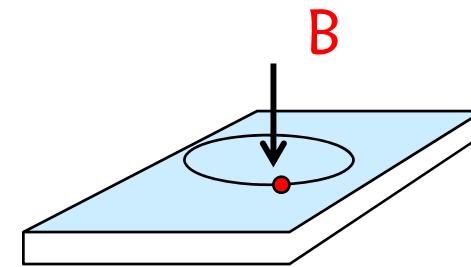


Derive the Cyclotron Formula

$$m^* = \frac{qB_0}{2\pi v_0}$$

For an particle in (x-y) plane with B-field in z-direction,
the Lorentz force is ...

$$\frac{m^* v^2}{r_0} = qv \times B_z = qvB_z$$



$$v = \frac{qB_0 r_0}{m^*}$$

$$\tau = \frac{2\pi r_0}{v} = \frac{2\pi m^*}{qB_0}$$

$$v_0 \equiv \frac{1}{\tau} = \frac{qB_0}{2\pi m^*}$$

$$\omega_0 = 2\pi v_0 = \frac{qB_0}{m^*}$$

Conclusions

- 1) E-k diagram/constant energy surfaces are simple ways to represent the locations where electrons can sit. They arise from the solution of Schrodinger equation in periodic lattice.
- 2) E-k diagram and energy bands contain equivalent information. In principle, any one can be used to construct the other.
- 3) Experimental measurements are key to making sure that the theoretical calculations are correct. We will discuss them in the next class.